
Program

Thursday, September 24

09:25 – 09:30 Opening Remarks

Session 1

Chair: Hyeonsik Cheong

09:30 – 10:00 Hyobin Yoo (Sogang Univ.) Invited-K1
Atomic and electronic reconstruction at van der Waals interface in twisted 2-D materials

10:00 – 10:30 Yuya Shimazaki (ETH Zurich) Invited-J1
Strongly correlated electrons in a moiré superlattice probed with exciton spectroscopy

10:30 – 11:00 Can-Li Song (Tsinghua Univ.) Invited-C1
Fulleride superconductivity at the two-dimensional limit

11:00 – 11:15 Break

Session 2

Chair: Hongtao Yuan

11:15 – 11:45 Ding Zhang (Tsinghua Univ.) Invited-C2
Ising pairing in few-layer stanene and modulation of superconductivity via lithium intercalation

11:45 – 12:15 Kosuke Nagashio (Univ. of Tokyo) Invited-J2
In-plane ferroelectricity in monolayer SnS

12:15 – 13:15 Lunch

Session 3

Chair: Yoshihiro Iwasa

13:15 – 13:45 Toshiaki Enoki (Tokyo Inst. Tech.) Invited-J3
Magnetism of Nanographene-based Nanoporous Carbon and its Applications

13:45 – 14:15 Sung-Yool Choi (KAIST) Invited-K2
2D Heterojunctions for High-Performance Electronic and Optoelectronic Devices

14:15 – 14:45 Tomoki Machida (Univ. of Tokyo) Invited-J4
Quantum transport in van der Waals junctions of graphene and h-BN

14:45 – 15:15 Sang Wook Lee (Ewha Womans Univ.) Invited-K3
Fowler-Nordheim tunneling through 2D atomic layers

15:15 – 15:30 Break

Session 4

Chair: Young-Woo Son

15:30 – 16:00 Yi Zhang (Nanjing Univ.) Invited-C3
Controllable Growth and Electronic Structures of 2D Transition Metal
Dichalcogenides Thin Films

16:00 – 16:30 Hyeon Suk Shin (UNIST) Invited-K4
Ultralow-dielectric-constant amorphous boron nitride

16:30 – 16:45 Yijun Yu (Fudan Univ.) Contributed-C1
High-temperature superconductivity in monolayer $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+\delta}$

16:45 – 17:00 Suhan Son (Seoul National Univ.) Contributed-K1
Strongly adhesive dry transfer technique by polycaprolactone

17:00 – 17:15 Hideki Matsuoka (Univ. of Tokyo) Contributed-J1
Magnetic van der Waals heterostructures with Zeeman-type spin-orbit-interaction

17:15 – 17:30 Cheng Chen (Shanghaitech Univ.) Contributed-C2
Observation of topological electronic structure in a quasi-1D superconductor

17:30 – 18:30 Poster Session

Friday, September 25

Session 5

Chair: Taishi Takenobu

09:30 – 10:00 Katsuaki Sugawara (Tohoku Univ.) Invited-J5
The electronic state of atomic-layer TMDs studied by high-resolution ARPES

10:00 – 10:30 Joon Ik Jang (Sogang Univ.) Invited-K5
Boosting optical responses of two-dimensional semiconducting transition metal
dichalcogenides

10:30 – 11:00 Qing Zhang (Peking Univ.) Invited-C4
Stimulated Emission in Solution-processed Two-dimensional Perovskite
Semiconductor

11:00 – 11:15 **Break**

Session 5

Chair: Yi Zhang

11:15 – 11:45 Jian Wang (Peking Univ.) Invited-C4
High-Chern-Number and High-Temperature Quantum Hall Effect without Landau Levels

11:45 – 12:15 Michihisa Yamamoto (RIKEN) Invited-J6
Electron transport in a correlated quantum Hall antiferromagnetic state of bilayer graphene

12:15 – 12:45 Yujun Deng (Fudan Univ.) Invited-C6
Quantum Anomalous Hall Effect in Few-layer MnBi_2Te_4

12:45 – 13:00 **Closing** **Yoshihiro Iwasa**

Posters

(17:30 – 18:30, Thursday, September 24)

- Poster-C1 Cheng Chen (Peking Univ.)
Zero-energy bound states in the high-temperature superconductors at the two-dimensional limit
- Poster-C2 Qiuyu Shang (Institute of Semiconductors, CAS)
Exciton–Polariton in a Continuous-Wave Optically Pumped Perovskite Laser
- Poster-C3 Miao-Ling Lin (Peking Univ.)
The angle-resolved polarized Raman scattering in anisotropic layered materials
- Poster-C4 Dinghui Wang (Nanjing Univ.)
Large Dynamical Axion Field in Topological Antiferromagnetic Insulator $\text{Mn}_2\text{Bi}_2\text{Te}_5$
- Poster-C5 Dongjing Lin (Nanjing Univ.)
Effects of dimensionality on the charge-density-wave order in 2H transition metal dichalcogenides
- Poster-C6 Xuedong Xie (Nanjing Univ.)
Band engineering in epitaxial monolayer transition metal dichalcogenides alloy $\text{Mo}_x\text{W}_{1-x}\text{Se}_2$ thin films
- Poster-C7 Haolin Wang (Nanjing Univ.)
Local conduction at BiFeO_3 - CoFe_2O_4 two-dimensional tubular interfaces
- Poster-C8 Yichi Zhang (Peking Univ.)
A native oxide high- κ gate dielectric for 2D electronics
- Poster-C9 Xuehan Zhou (Peking Univ.)
Molecular Beam Epitaxy of High-mobility 2D Oxychalcogenide Semiconductors
- Poster-J1 Yoshihiro Iwasa (Univ. of Tokyo)
Vortex matter in 2D Superconductors
- Poster-J2 Seiya Suzuki (NIMS)
Segregation growth of germanene at interfaces between van der Waals materials and Ag(111)
- Poster-J3 Hiroki Sugawara (Tohoku Univ.)
Process development and crystal quality evaluation of van der Waals nanocapacitor using graphene/h-BN heterostructures stacked by transfer/stacking method
- Poster-J4 Yan Zhang (Kyoto Univ.)
Charge Transfer and Magnetic Proximity Effect in van der Waals Heterostructure of Monolayer MoSe_2 and Double-layered Manganese Oxide
- Poster-J5 Yuma Tanaka (Univ. of Tokyo)
Observation of the layer dependent electronic structures in atomically thin WTe_2

flakes

- Poster-J6 Miuko Tanaka (Univ. of Tokyo)
Electron transport mechanism in a correlated quantum Hall antiferromagnetic state of bilayer graphene
- Poster-J7 Naofumi Sato (Tohoku Univ.)
Controlled synthesis of graphene nanoribbons from liquid phase catalyst
- Poster-J8 Tappei Kawakami (Tohoku Univ.)
Electronic states of monolayer VTe₂ thin film studied by high-resolution ARPES
- Poster-J9 Jiang Pu (Nagoya Univ.)
Chiral electroluminescence in monolayer heterojunctions
- Poster-K1 Sohwi Kim (Konkuk Univ.)
Synaptic Performance with Improved Linearity and Endurance by modulating Pb(Zr_{0.52}Ti_{0.48})O₃/Nb doped SrTiO₃ Interface Barrier
- Poster-K2 Yeryun Cheon (Sogang Univ.)
Interlayer coupling and structural phase transition in few-layer 1T' and T_d MoTe₂
- Poster-K3 Jinwon Lee (POSTECH)
Realization of a Honeycomb-Lattice Mott Insulating State on 1T-TaS₂
- Poster-K4 Junho Seo (CALDES, IBS & POSTECH)
Tunable high-temperature itinerant antiferromagnetism in a van der Waals magnet
- Poster-K5 EuiHyoun Ryu (Korea Univ.)
ReS₂ based *pn* Heterojunction Device
- Poster-K6 Seohyun Nam (Sogang Univ.)
Population dynamics of excitons and biexcitons in a 2D halide perovskite single crystal
- Poster-K7 Taewook Kim (Yonsei Univ.)
2D TMD Channel with 1D ZnO Nanowire for Nonvolatile Trap Memory
- Poster-K8 Yongjae Cho (Yonsei Univ.)
Low voltage operating nonvolatile memory transistor with MoTe₂ channel and P(VDF-TrFE) ferroelectrics
- Poster-K9 Yoonseok Kim (Korea Univ.)
Atomic-Layer-Confined Multiple Quantum Wells Enabled by Monolithic Bandgap Engineering of Transition Metal Dichalcogenides
- Poster-K10 Hyeok Jun Jin (KAIST)
Atomically thin Schottky junction with a gap-mode plasmon for Enhanced photoresponsivity in MoS₂ based photodetector
- Poster-K11 Jun Ho Lee (Konkuk Univ.)
High-speed residue-free transfer of two-dimensional materials using PDMS stamp and water infiltration